

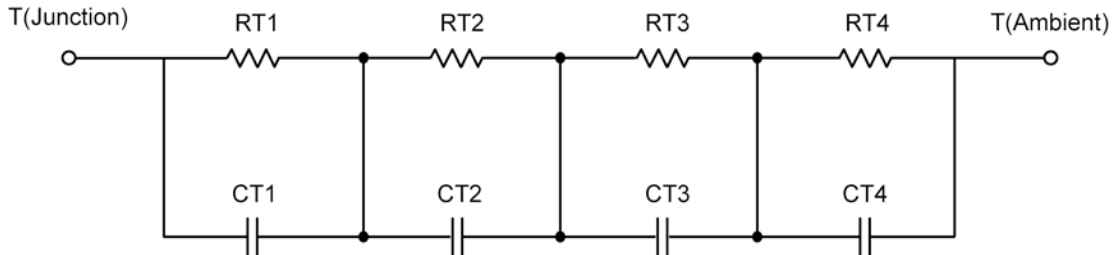
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-Spice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	10.5911	398.5209 m	N/A
RT2	12.7251	249.5940 m	N/A
RT3	1.2919	697.2851 m	N/A
RT4	56.3919	1.0546	N/A
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	15.4736 m	3.0860 m	N/A
CT2	130.6264 m	1.1149 m	N/A
CT3	772.0420 u	14.4835 m	N/A
CT4	1.2194	16.4906 m	N/A

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	1.1540	568.1206 m	N/A
RF2	15.7975	532.1878 m	N/A
RF3	12.2887	531.8931 m	N/A
RF4	51.7598	767.7985 m	N/A
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	619.3526 u	691.0242 u	N/A
CF2	13.0375 m	4.6359 m	N/A
CF3	217.9451 m	112.7287 u	N/A
CF4	1.1007	7.5926 m	N/A

Note

NA indicates not applicable

